NSN 5961-00-063-5388

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View Online at https://aerobasegroup.com/nsn/5961-00-063-5388 **Inclosure Material:** Metal **Overall Length:** 0.750 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 15.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes base current, dc and 10.00 amperes collector current, dc **Power Rating Per Characteristic:** 150.0 watts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 wire hook **Specification Data:** 80131-release4782 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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